

Isc N-Channel MOSFET Transistor

STW57N65M5

• FEATURES

- With TO-262(I2PAK) packaging
- · High speed switching
- · Low gate input resistance
- · Standard level gate drive
- · Easy to use
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

- Power supply
- Switching applications

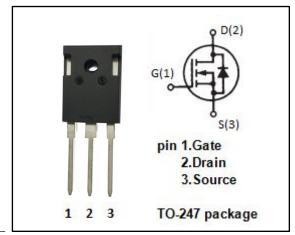


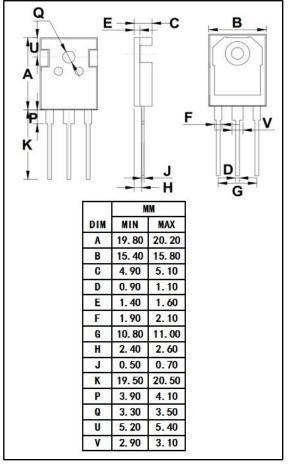
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	650	V
V _{GSS}	Gate-Source Voltage	±25	V
Ι _D	Drain Current-Continuous@ T_c =25° C T_c =100° C	42 26.5	А
I _{DM}	Drain Current-Single Pulsed	168	А
P _D	Total Dissipation	250	W
Tj	Operating Junction Temperature	150	°C
T _{stg}	Storage Temperature	-55~150	°C

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	0.5	°C/W





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ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 1mA	650			V
V _{GS(th)}	Gate Threshold Voltage	V_{DS} = $V_{GS}V$; I_D =0.25mA	3		5	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =21A		56	63	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±25V;V _{DS} = 0V			±0.1	μА
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 650V; V _{GS} = 0V;Tj=25℃ Tj=125℃			1 100	μА
V _{SDF}	Diode forward voltage	I _{SD} =42A, V _{GS} = 0 V			1.5	V

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